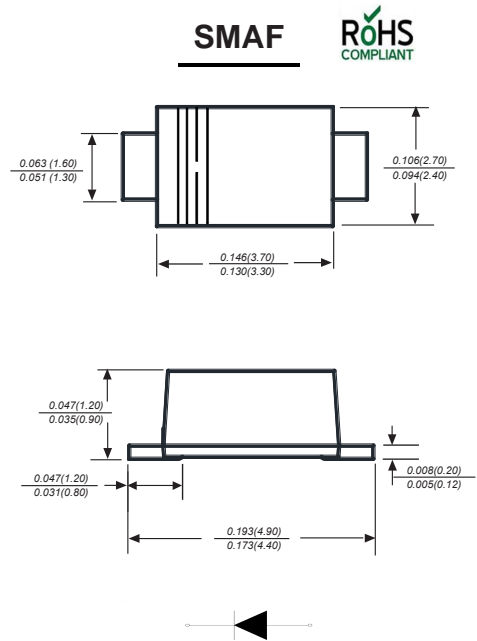


SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

Features

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ For surface mounted applications
- ◆ Metal silicon junction, majority carrier conduction
- ◆ Low power loss, high efficiency
- ◆ Built-in strain relief, ideal for automated placement
- ◆ High forward surge current capability
- ◆ High temperature soldering guaranteed:
260 °C/10 seconds at terminals



Dimensions in inches and (millimeters)

Mechanical Data

Case: JEDEC SMAF molded plastic body
 Terminals: Solderable per MIL-STD-750, Method 2026
 Polarity: Color band denotes cathode end
 Mounting Position: Any
 Weight: 0.0018 ounce, 0.064 grams

Maximum Ratings And Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

| Parameter | SYMBOLS | SS22F | SS23F | SS24F | SS25F | SS26F | SS28F | SS210F | SS2150F | SS2200F | UNITS |
|---|-----------------|--------------|--------------|--------------|--------------|--------------|--------------|---------------|----------------|----------------|-------|
| | | MDD SS22F | MDD SS23F | MDD SS24F | MDD SS25F | MDD SS26F | MDD SS28F | MDD SS210F | MDD SS2150F | MDD SS2200F | |
| Maximum repetitive peak reverse voltage | V_{RMM} | 20 | 30 | 40 | 50 | 60 | 80 | 100 | 150 | 200 | V |
| Maximum RMS voltage | V_{RMS} | 14 | 21 | 28 | 35 | 42 | 56 | 70 | 105 | 140 | V |
| Maximum DC blocking voltage | V_{DC} | 20 | 30 | 40 | 50 | 60 | 80 | 100 | 150 | 200 | V |
| Maximum average forward rectified current at TL (see fig.1) | $I_{(AV)}$ | 2.0 | | | | | | | | | A |
| Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method) | I_{FSM} | 50 | | | | | | | | | A |
| Maximum instantaneous forward voltage at 2.0A | V_F | 0.55 | | 0.70 | | 0.85 | | 0.95 | | | V |
| Maximum DC reverse current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=125^\circ\text{C}$ | I_R | 0.5 | | | | | | 0.2 | | | mA |
| | | 10.0 | | | | 5.0 | | 2.0 | | | |
| Typical junction capacitance (NOTE 1) | C_J | 160 | | | 80 | | | | | | pF |
| Typical thermal resistance (NOTE 2) | $R_{\theta JA}$ | 75.0 | | | | | | | | | °C/W |
| Operating junction temperature range | T_J | -55 to +125 | | | | | | | | | °C |
| Storage temperature range | T_{STG} | -55 to +150 | | | | | | | | | °C |

Note: 1. Measured at 1.0MHz and applied reverse voltage of 4.0V D.C.
 2. P.C.B. mounted with 2.0x2.0" (5.0x5.0cm) copper pad areas.
 3. The typical data above is for reference only.

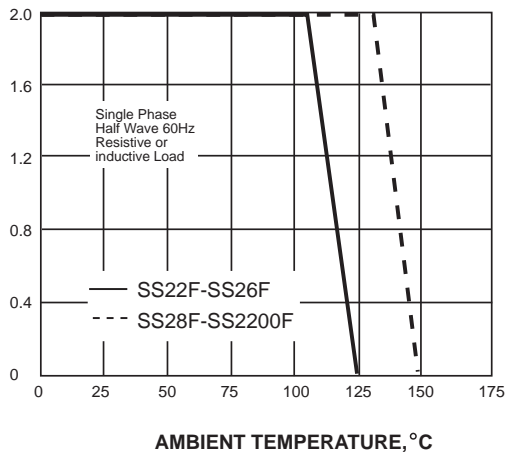
SS22F THRU SS2200F

Reverse Voltage - 20 to 200 Volts Forward Current - 2.0 Ampere

Typical Characteristics

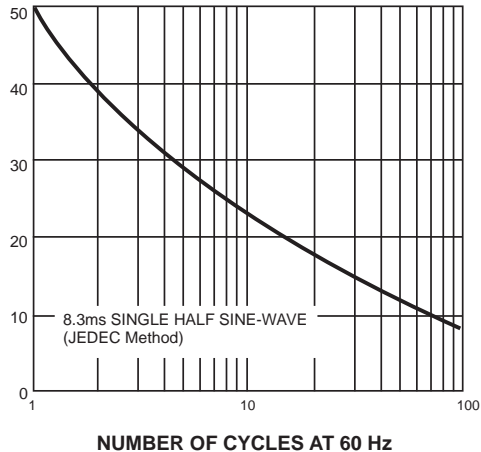
AVERAGE FORWARD RECTIFIED CURRENT, AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE



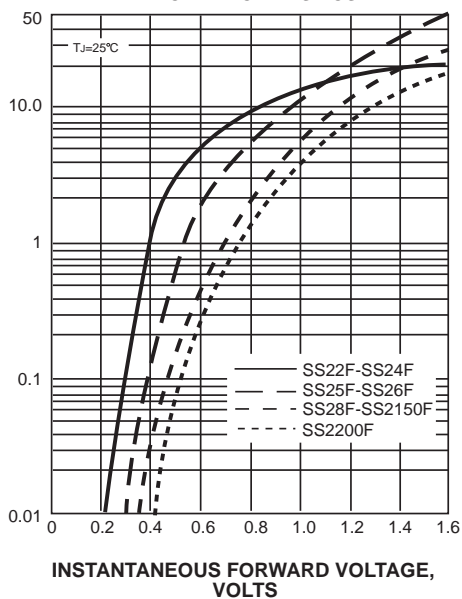
PEAK FORWARD SURGE CURRENT, AMPERES

FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT



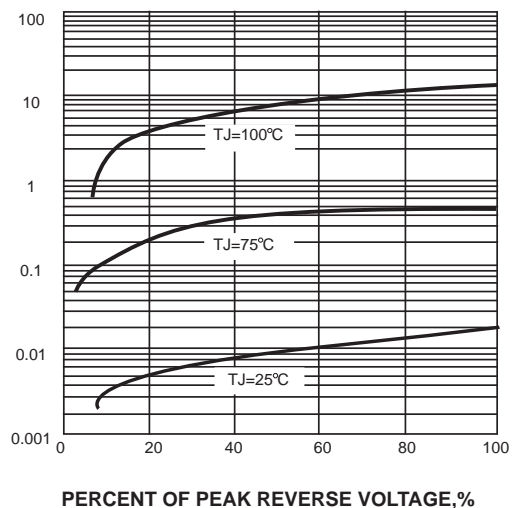
INSTANTANEOUS FORWARD CURRENT, AMPERES

FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



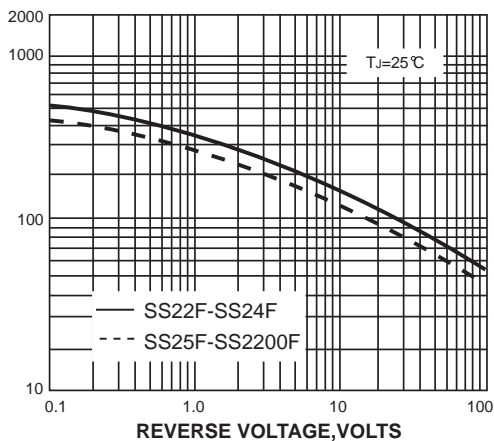
INSTANTANEOUS REVERSE CURRENT, MILLIAMPERES

FIG. 4-TYPICAL REVERSE CHARACTERISTICS



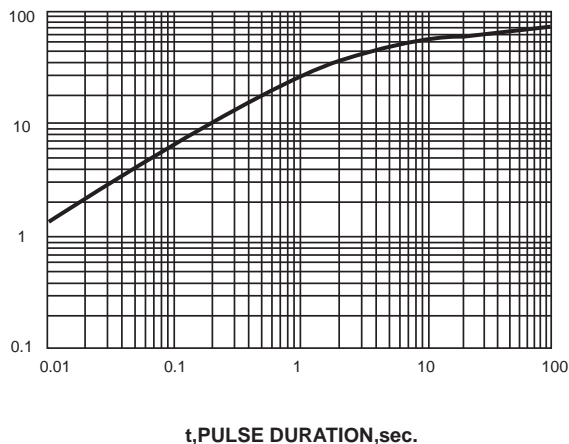
JUNCTION CAPACITANCE, pF

FIG. 5-TYPICAL JUNCTION CAPACITANCE



TRANSIENT THERMAL IMPEDANCE, °C/W

FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE



The curve above is for reference only.